

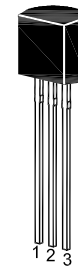
2SD882S

NPN Silicon Epitaxial Planar Transistor

for the output stage of 0.75 W audio, voltage regulator, and relay driver.

The transistor is subdivided into three groups Q, P and E, according to its DC current gain.

On special request, these transistors can be manufactured in different pin configurations.



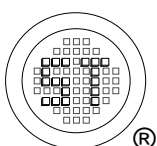
1. Emitter 2. Collector 3. Base
TO-92 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector to Base Voltage	V_{CBO}	40	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5	V
Collector Current	I_C	3	A
Power Dissipation	P_{tot}	750	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at $V_{CE} = 2\text{ V}$, $I_C = 1\text{ A}$ at $V_{CE} = 2\text{ V}$, $I_C = 20\text{ mA}$	Current Gain Group Q P E	h_{FE}	100	-	200	-
		h_{FE}	160	-	320	-
		h_{FE}	200	-	400	-
		h_{FE}	30	-	-	-
Collector Base Cutoff Current at $V_{CB} = 30\text{ V}$	I_{CBO}	-	-	1	μA	
Emitter Base Cutoff Current at $V_{EB} = 3\text{ V}$	I_{EBO}	-	-	1	μA	
Collector Base Breakdown Voltage at $I_C = 100\ \mu\text{A}$	$V_{(BR)CBO}$	40	-	-	V	
Collector Emitter Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CEO}$	30	-	-	V	
Emitter Base Breakdown Voltage at $I_E = 10\ \mu\text{A}$	$V_{(BR)EBO}$	5	-	-	V	
Collector Emitter Saturation Voltage at $I_C = 2\text{ A}$, $I_B = 200\text{ mA}$	$V_{CE(sat)}$	-	-	0.5	V	
Base Emitter Saturation Voltage at $I_C = 2\text{ A}$, $I_B = 200\text{ mA}$	$V_{BE(sat)}$	-	-	2	V	
Transition Frequency at $V_{CE} = 5\text{ V}$, $I_C = 0.1\text{ A}$, $f = 100\text{ MHz}$	f_T	-	90	-	MHz	
Collector Output Capacitance at $V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{ob}	-	45	-	pF	



SEMTECH ELECTRONICS LTD.



ISO/TS 16949 : 2009 Certificate No. 18071300
 ISO14001 : 2004 Certificate No. 7116
 ISO 9001 : 2008 Certificate No. 90719410
 BS-OHSAS 18001 : 2007 Certificate No. 7116
 IECQ QC 080000 Certificate No. PFC-18P4-1483

Dated: 22/02/2016 CL Rev: 02